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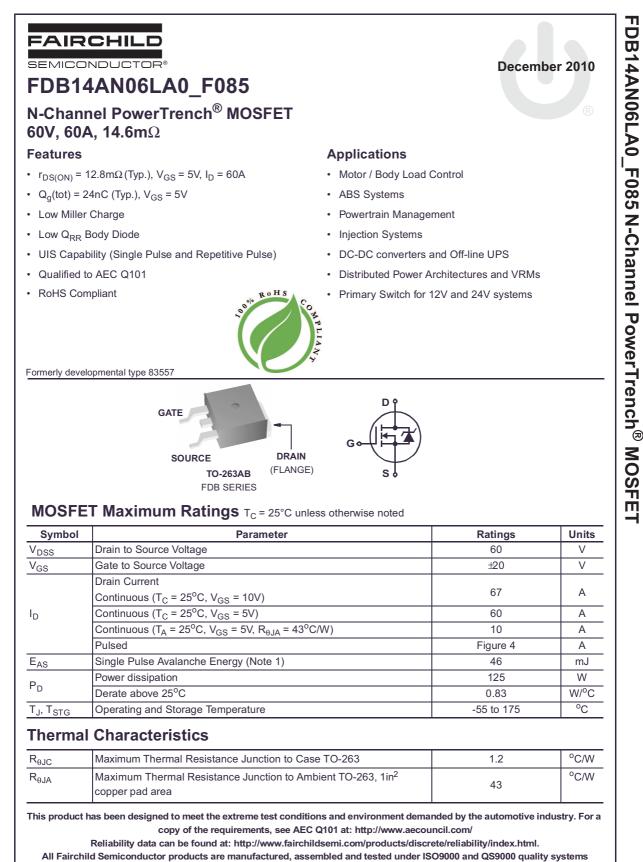


ON Semiconductor®

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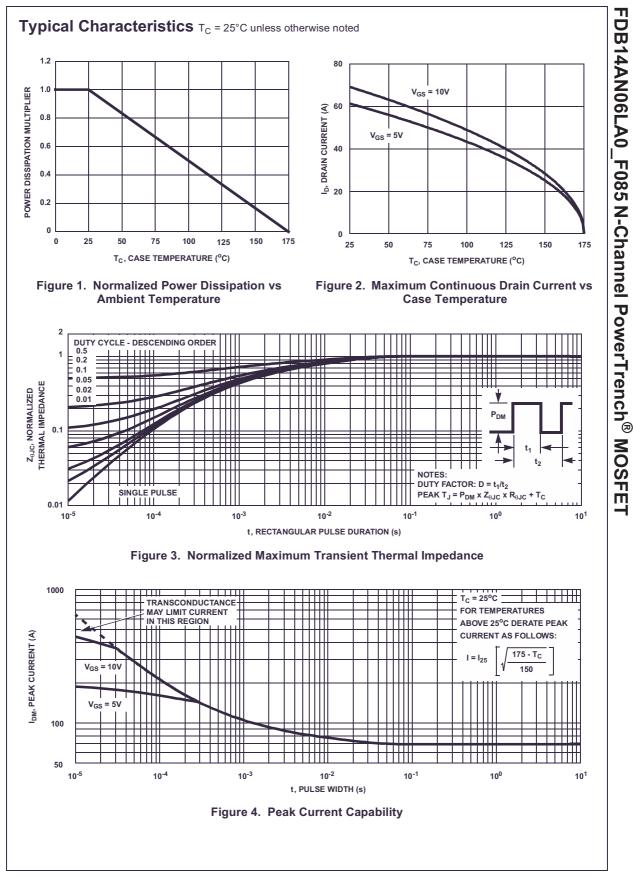


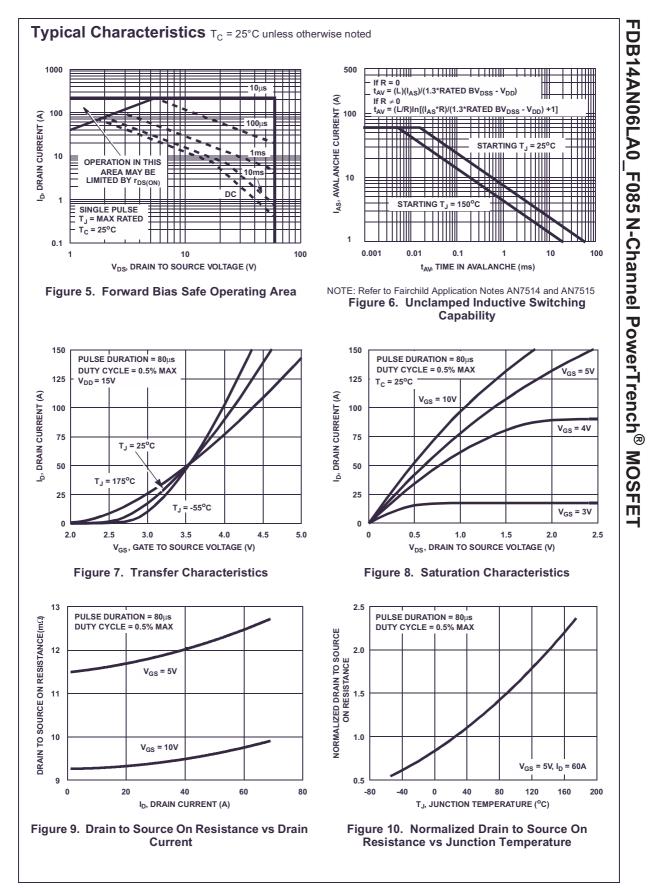
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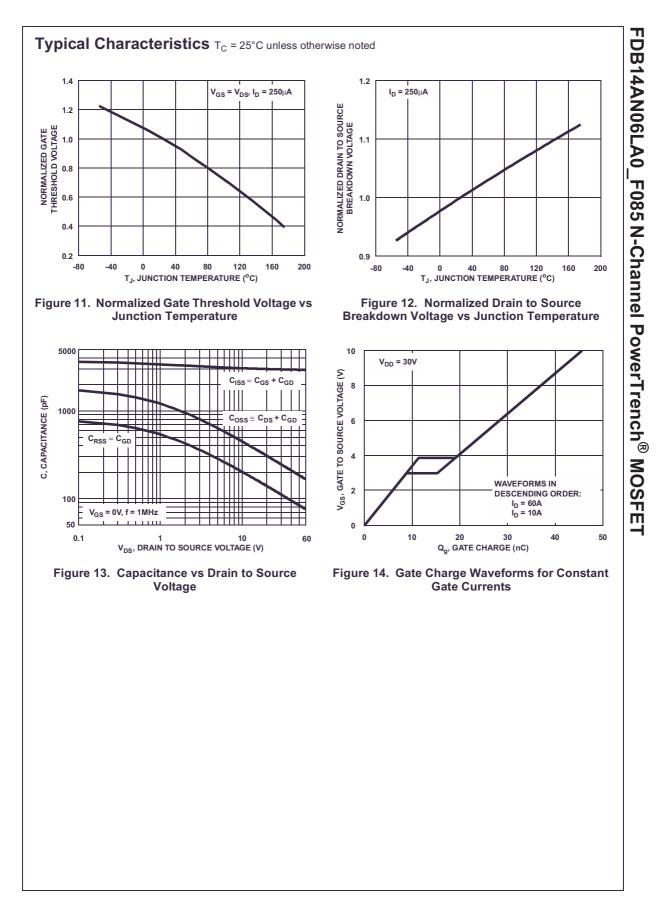
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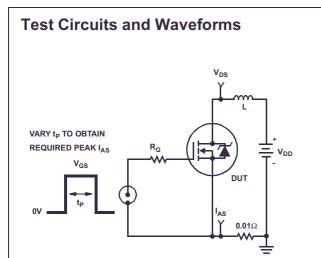
	Marking	Device	Package	Reel Size	Tape V	Vidth	Quar	ntity	
FDB14AN06LA0		FDB14AN06LA0_F085	TO-263AB	330mm	24mm		800 units		
Electric	al Chai	racteristics T _c = 25°C	C unless otherwise	noted					
Symbol		Parameter	Test Conditions		Min Typ		Max Uni		
Off Chara	octoristic	<u>`</u>			•	•	-		
			L = 050. A V	- 0) (60	1		V	
B _{VDSS}	Drain to a	Source Breakdown Voltage	I _D = 250μA, V ₀ V _{DS} = 50V	38 - UV	60	-	-	V	
I _{DSS} Zero Gat		e Voltage Drain Current	$V_{\rm DS} = 50V$ $V_{\rm GS} = 0V$	T _C = 150°C	-	-	1 250	μA	
I _{GSS}	Gate to S	Gate to Source Leakage Current		1 _C = 150 C	-	-	±100	nA	
1655	outo to c		V _{GS} = ±20V				100	10.0	
On Chara	cteristic	S							
V _{GS(TH)}	Gate to S	Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D}$	= 250µA	1	-	3	V	
			I _D = 67A, V _{GS}		-	0.0102	0.0116		
r _{DS(ON)}	Drain to S	Source On Resistance	$I_D = 60A, V_{GS}$		-	0.0128	0.0146	Ω	
DS(ON)			I _D = 60A, V _{GS} T _J = 175 ^o C	= 5V,	-	0.028	0.033		
Dynamic	Charact	eristics							
C _{ISS}	Input Cap	pacitance				2900	-	pF	
C _{OSS}		apacitance	$V_{DS} = 25V, V_{C}$	_{3S} = 0V,	-	270	-	pF	
C _{RSS}	-	Transfer Capacitance	f = 1MHz		-	115	-	pF	
Q _{g(TOT)}	-	e Charge at 5V	$V_{GS} = 0V$ to 5	V		24	31	nC	
Q _{g(TH)}	-	d Gate Charge	V _{GS} = 0V to 1		-	3.0	3.9	nC	
Q _{gs}	Gate to S	Source Gate Charge		$I_{\rm D} = 60{\rm A}$	-	12	-	nC	
Q _{gs2}	Gate Cha	arge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	9.1	-	nC	
Q _{gd}	Gate to D	Drain "Miller" Charge		-		7.9	-	nC	
Switching	a Charac	cteristics (V _{GS} = 5V)							
t _{on}	Turn-On			V _{DD} = 30V, I _D = 60A		-	276	ns	
t _{d(ON)}	_	Delay Time				15	-	ns	
t _r	Rise Tim		Vpp = 30V. lp			169	-	ns	
t _{d(OFF)}	Turn-Off	Turn-Off Delay Time		$V_{GS} = 5V, R_{GS} = 5.1\Omega$		24	-	ns	
t _f	Fall Time					50	-	ns	
t _{OFF}	Turn-Off	Time		-		-	109	ns	
	urce Dio	de Characteristics	•						
		o Drain Diode Voltage	I _{SD} = 60A		-	-	1.25	V	
V _{SD}		o orani oloue voltaye	I _{SD} = 30A		-	-	1.0	V	
t _{rr}	_	Recovery Time	I_{SD} = 60A, dI_{SD}/dt = 100A/µs		-	-	33	ns	
Q _{RR}	Reverse	Recovered Charge	I _{SD} = 60A, dI _S	_D /dt = 100A/µs	-	-	29	nC	

FDB14AN06LA0_F085 N-Channel PowerTrench[®] MOSFET









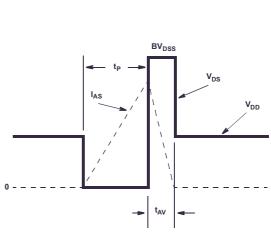


Figure 15. Unclamped Energy Test Circuit

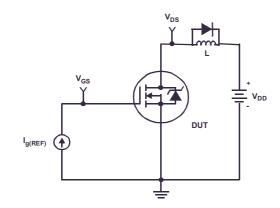


Figure 17. Gate Charge Test Circuit

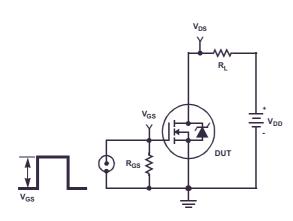
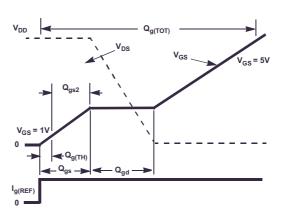
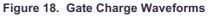
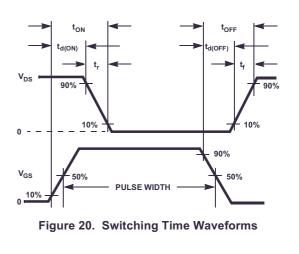


Figure 19. Switching Time Test Circuit

Figure 16. Unclamped Energy Waveforms







FDB14AN06LA0_F085 N-Channel PowerTrench[®] MOSFET

Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-263 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

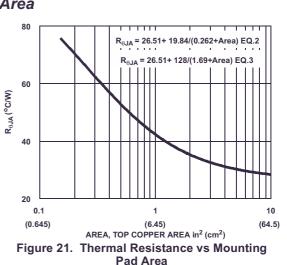
Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta,JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\theta JA} = 26.51 + \frac{19.84}{(0.262 + Area)}$$
(EQ. 2)

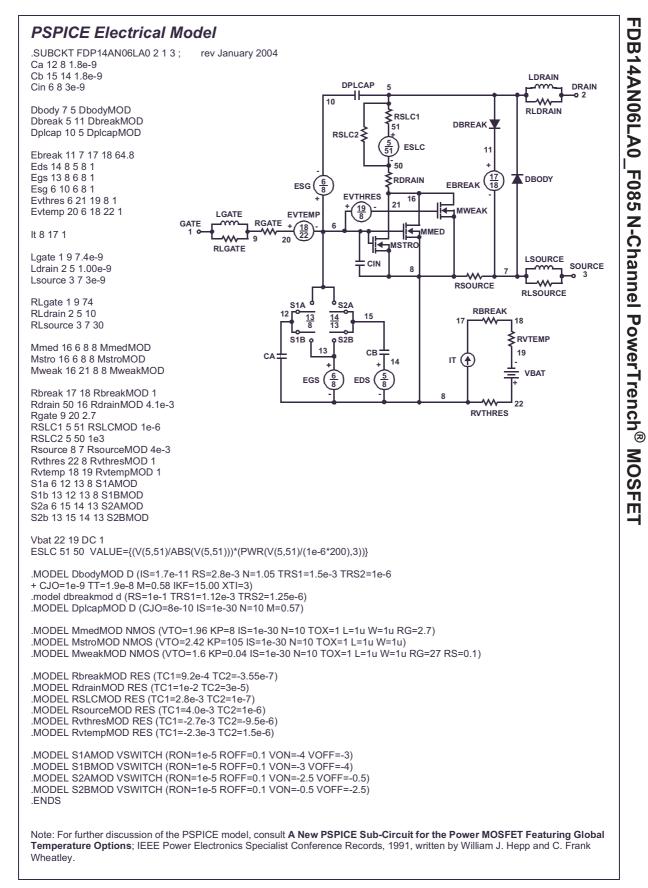
$$R_{\theta JA} = 26.51 + \frac{128}{(1.69 + Area)}$$
(EQ. 3)

Area in Centimeters Squared

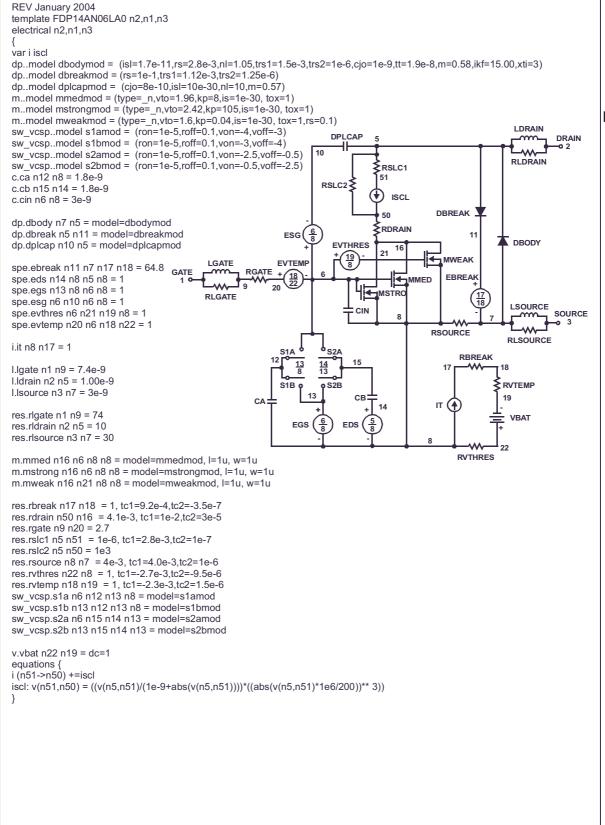


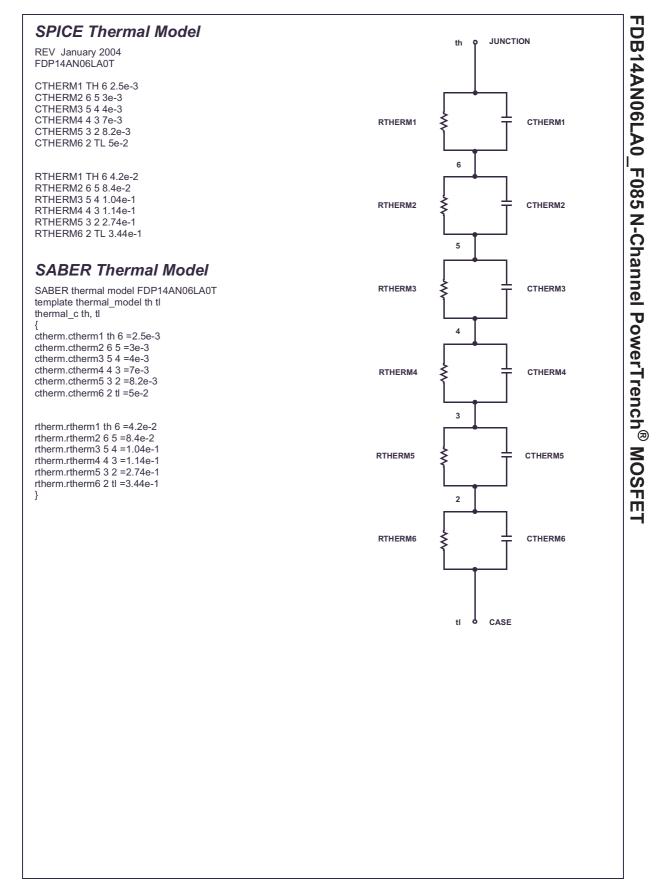
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